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April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

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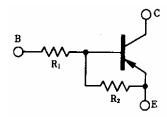


# COMPOUND TRANSISTOR HR1 SERIES

# on-chip resistor PNP silicon epitaxial transistor For mid-speed switching

#### **FEATURES**

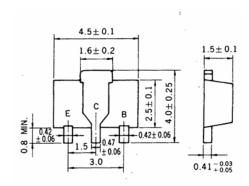
- Up to 2A high current drives such as IC outputs and actuators available
- On-chip bias resistor
- · Low power consumption during drive



#### **HR1 SERIES LISTS**

Products	Marking	R <sub>1</sub> (kΩ)	R <sub>2</sub> (kΩ)
HR1A3M	MP	1.0	1.0
HR1F3P	MQ	2.2	10
HR1L3N	MR	4.7	10
HR1A4M	MS	10	10
HR1L2Q	MT	0.47	4.7
HR1F2Q	MU	0.22	2.2
HR1A4A	MX	ı	10

#### **PACKAGE DRAWING (UNIT: mm)**



**Electrode Connection** 

- E. Emitter
- C. Collector
- R. Base

#### ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Parameter	Symbol	Ratings	Unit
Collector to base voltage	VcBo	-60	V
Collector to emitter voltage	VCEO	-60	V
Emitter to base voltage	VEBO	-10	V
Collector current (DC)	Ic(DC)	-1.0	Α
Collector current (Pulse)	IC(pulse) Note1	-2.0	Α
Base current (DC)	I <sub>B(DC)</sub>	-0.02	Α
Total power dissipation	PT Note2	2.0	W
Junction temperature	Tj	150	°C
Storage temperature	T <sub>stg</sub>	−55 to +150	°C

**Notes 1.** PW  $\leq$  10 ms, duty cycle  $\leq$  50 %

2. When 0.7 mm  $\times$  16 cm<sup>2</sup> ceramic board is used

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#### HR1A3M ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	$V_{CB} = -60 \text{ V}, I_E = 0$			-100	nA
DC current gain	h <sub>FE1</sub> Note	$V_{CE} = -2.0 \text{ V}, \text{ Ic} = -0.1 \text{ A}$	50			-
DC current gain	hFE2 Note	$V_{CE} = -2.0 \text{ V, } I_{C} = -0.5 \text{ A}$	100			_
DC current gain	hFE3 Note	$V_{CE} = -2.0 \text{ V}, \text{ Ic} = -1.0 \text{ A}$	50			-
Low level output voltage	Vol. Note	$V_{IN} = -5.0 \text{ V, Ic} = -0.4 \text{ A}$			-0.4	V
Low level input voltage	V <sub>IL</sub> Note	$V_{CE} = -5.0 \text{ V, } I_{C} = -100 \ \mu\text{A}$			-0.3	V
Input resistance	R <sub>1</sub>		0.7	1.0	1.3	kΩ
E-to-B resistance	R <sub>2</sub>		0.7	1.0	1.3	kΩ

**Note** PW  $\leq$  350  $\mu$ s, duty cycle  $\leq$  2 %

#### HR1F3P

#### **ELECTRICAL CHARACTERISTICS (TA = 25°C)**

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	$V_{CB} = -60 \text{ V}, I_E = 0$			-100	nA
DC current gain	h <sub>FE1</sub> Note	$V_{CE} = -2.0 \text{ V}, I_{C} = -0.1 \text{ A}$	150			ı
DC current gain	hFE2 Note	$V_{CE} = -2.0 \text{ V}, \text{ Ic} = -0.5 \text{ A}$	100			-
DC current gain	h <sub>FE3</sub> Note	$V_{CE} = -2.0 \text{ V, Ic} = -1.0 \text{ A}$	50			_
Low level output voltage	Vol. Note	V <sub>IN</sub> = -5.0 V, Ic = -0.3 A			-0.3	V
Low level input voltage	V <sub>IL</sub> Note	$V_{CE} = -5.0 \text{ V}, \text{ Ic} = -100 \ \mu\text{A}$			-0.3	V
Input resistance	R <sub>1</sub>		1.54	2.2	2.86	kΩ
E-to-B resistance	R <sub>2</sub>		7	10	13	kΩ

**Note** PW  $\leq$  350  $\mu$ s, duty cycle  $\leq$  2 %

#### HR1L3N

#### **ELECTRICAL CHARACTERISTICS (TA = 25°C)**

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	$V_{CB} = -60 \text{ V}, I_E = 0$			-100	nA
DC current gain	hFE1 Note	$V_{CE} = -2.0 \text{ V, Ic} = -0.1 \text{ A}$	150			Ī
DC current gain	hFE2 Note	$V_{CE} = -2.0 \text{ V}, \text{ Ic} = -0.5 \text{ A}$	100			ı
DC current gain	hfe3 Note	$V_{CE} = -2.0 \text{ V, Ic} = -1.0 \text{ A}$	50			Ī
Low level output voltage	Vol. Note	$V_{IN} = -5.0 \text{ V}, \text{ Ic} = -0.2 \text{ A}$			-0.3	V
Low level input voltage	V <sub>IL</sub> Note	$V_{CE} = -5.0 \text{ V, } I_{C} = -100 \ \mu\text{A}$			-0.3	V
Input resistance	R <sub>1</sub>		3.29	4.7	6.11	kΩ
E-to-B resistance	R <sub>2</sub>		7	10	13	kΩ

**Note** PW  $\leq$  350  $\mu$ s, duty cycle  $\leq$  2 %

2



HR1A4M ELECTRICAL CHARACTERISTICS (TA = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	$V_{CB} = -60 \text{ V}, I_E = 0$			-100	nA
DC current gain	h <sub>FE1</sub> Note	$V_{CE} = -2.0 \text{ V}, \text{ Ic} = -0.1 \text{ A}$	150			-
DC current gain	hFE2 Note	$V_{CE} = -2.0 \text{ V, } I_{C} = -0.5 \text{ A}$	100			_
DC current gain	hFE3 Note	$V_{CE} = -2.0 \text{ V}, \text{ Ic} = -1.0 \text{ A}$	50			-
Low level output voltage	Vol. Note	$V_{IN} = -5.0 \text{ V, Ic} = -0.1 \text{ A}$			-0.2	V
Low level input voltage	V <sub>IL</sub> Note	$V_{CE} = -5.0 \text{ V, } I_{C} = -100 \ \mu\text{A}$			-0.3	V
Input resistance	R <sub>1</sub>		7	10	13	kΩ
E-to-B resistance	R <sub>2</sub>		7	10	13	kΩ

**Note** PW  $\leq$  350  $\mu$ s, duty cycle  $\leq$  2 %

HR1L2Q ELECTRICAL CHARACTERISTICS (TA = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	V <sub>CB</sub> = -60 V, I <sub>E</sub> = 0			-100	nA
DC current gain	hFE1 Note	Vce = -2.0 V, Ic = -0.1 A	150			-
DC current gain	hFE2 Note	$V_{CE} = -2.0 \text{ V}, \text{ Ic} = -0.5 \text{ A}$	100			_
DC current gain	hFE3 Note	Vce = -2.0 V, Ic = -1.0 A	50			-
Low level output voltage	Vol. Note	$V_{IN} = -5.0 \text{ V}, \text{ Ic} = -0.5 \text{ A}$			-0.55	V
Low level input voltage	V <sub>IL</sub> Note	$V_{CE} = -5.0 \text{ V}, \text{ Ic} = -100 \ \mu\text{A}$			-0.3	V
Input resistance	R <sub>1</sub>		329	470	611	Ω
E-to-B resistance	R <sub>2</sub>		3.29	4.7	6.11	kΩ

**Note** PW  $\leq$  350  $\mu$ s, duty cycle  $\leq$  2 %

### HR1F2Q ELECTRICAL CHARACTERISTICS (TA = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	$V_{CB} = -60 \text{ V}, I_E = 0$			-100	nA
DC current gain	hFE1 Note	$V_{CE} = -2.0 \text{ V, Ic} = -0.1 \text{ A}$	100			-
DC current gain	hFE2 Note	$V_{CE} = -2.0 \text{ V}, \text{ Ic} = -0.5 \text{ A}$	100			-
DC current gain	h <sub>FE3</sub> Note	$V_{CE} = -2.0 \text{ V}, \text{ Ic} = -1.0 \text{ A}$	50			_
Low level output voltage	Vol. Note	$V_{IN} = -5.0 \text{ V}, \text{ Ic} = -0.5 \text{ A}$			-0.55	V
Low level input voltage	V <sub>IL</sub> Note	$V_{CE} = -5.0 \text{ V}, \text{ Ic} = -100 \ \mu\text{A}$			-0.3	V
Input resistance	R <sub>1</sub>		154	220	286	Ω
E-to-B resistance	R <sub>2</sub>		1.54	2.2	2.86	kΩ

**Note** PW  $\leq$  350  $\mu$ s, duty cycle  $\leq$  2 %

Data Sheet D16184EJ4V0DS



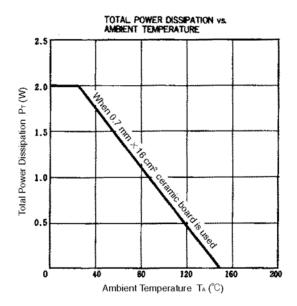
HR1A4A ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C)

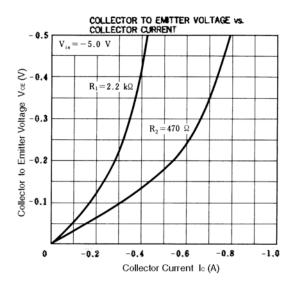
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	$V_{CB} = -60 \text{ V}, I_E = 0$			-100	nA
DC current gain	hFE1 Note	$V_{CE} = -2.0 \text{ V, Ic} = -0.1 \text{ A}$	150			-
DC current gain	hFE2 Note	Vce = -2.0 V, Ic = -0.5 A	100			_
DC current gain	hfE3 Note	$V_{CE} = -2.0 \text{ V}, I_{C} = -1.0 \text{ A}$	50			=
Collector saturation voltage	V <sub>CE(sat)</sub> Note	Ic = -500  mA, IB = -10  mA		0.20	0.35	V
Low level input voltage	V <sub>IL</sub> Note	$V_{CE} = -5.0 \text{ V, } I_{C} = -100 \ \mu\text{A}$	-0.3		-1.5	V
E-to-B resistance	R <sub>2</sub>		7	10	13	kΩ

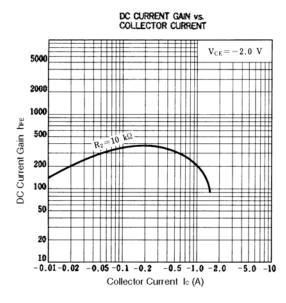
**Note** PW  $\leq$  350  $\mu$ s, duty cycle  $\leq$  2 %

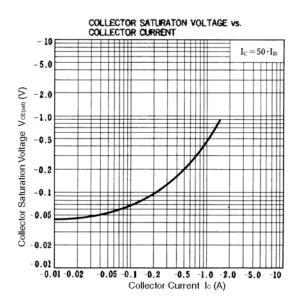


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